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Inclosure Material:

Metal all transistor

Overall Length:

0.210 inches all transistor

Terminal Length:

0.500 inches all transistor

Overall Diameter:

0.230 inches all transistor

Internal Configuration:

Junction contact all transistor

Electrode Internally-electrically Connected To Case:

Collector all transistor

Internal Junction Configuration:

Npn all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal all transistor

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

75.0 collector to base voltage/static/emitter open all transistor and 30.0 collector to emitter voltage/static/base open all transistor and 7.0 emitter to base voltage, static, collector open all transistor and 50.0 collector-to-emitter, resistance between base and emitter all transistor

Current Rating Per Characteristic:

500.00 milliamperes collector current, dc all transistor

Power Rating Per Characteristic:

3.0 watts small-signal input power, common-collector preset all transistor

Maximum Operating Temperature Per Measurement Point:

175.0 degrees celsius junction all transistor

Test Data Document:

05824-382955 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead all transistor

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fig:

A110a0